

TCC-106

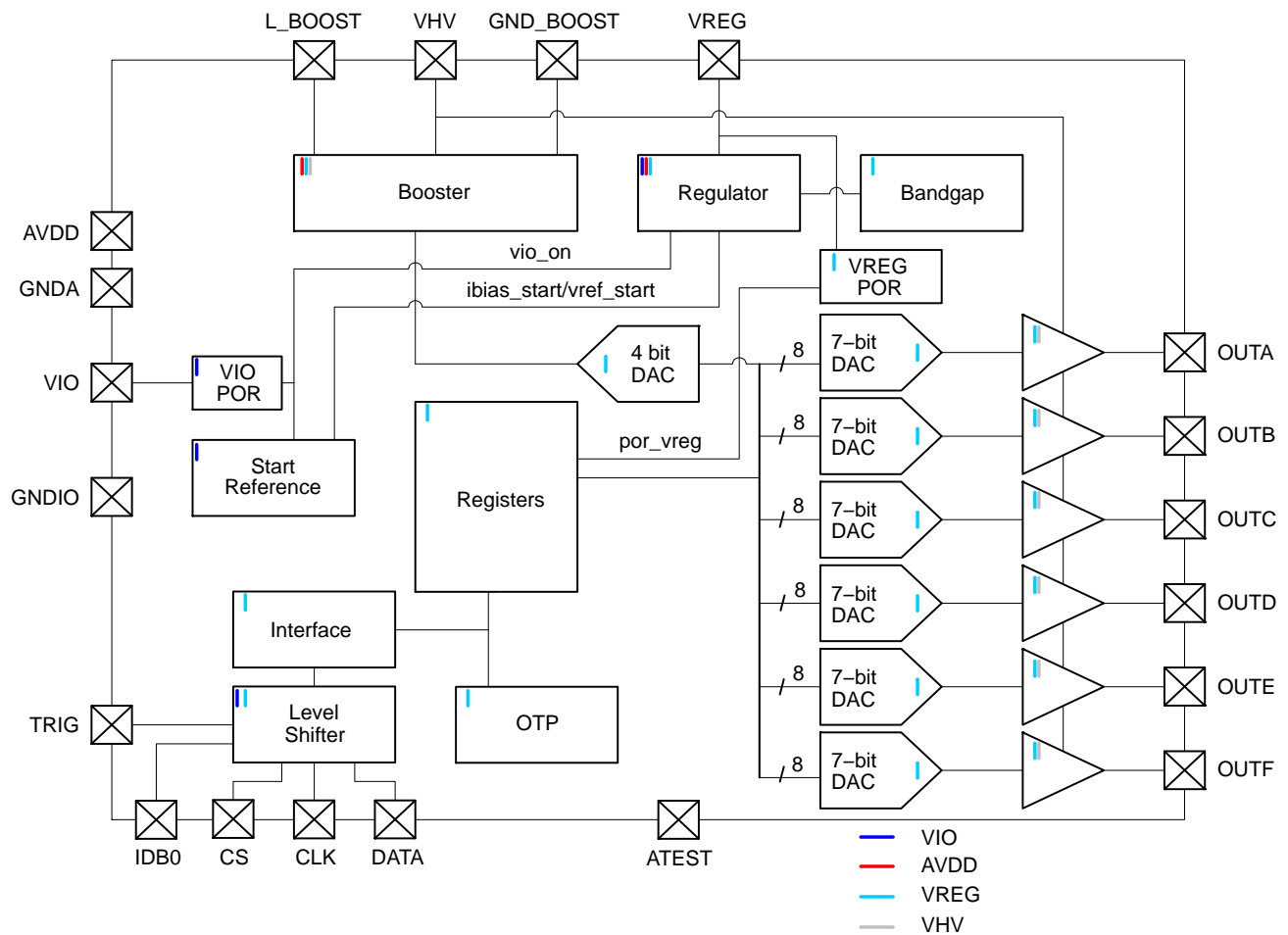


Figure 1. Control IC Functional Block Diagram

RDL Pin Out

Table 1. PAD DESCRIPTIONS

| Bump | Name | Type | Description | Max Voltage (Note 1) | RDL |
|------|-----------|-----------|---|-------------------------|-----|
| 1 | L_BOOST | AOH | Boost Inductor | 25 | B4 |
| 2 | AVDD | P | Analog Supply | 5.5 | B3 |
| 3 | GNDA | P | Analog Ground | 0 | C3 |
| 4 | TRIG | DIO | Trigger Signal Input (Note 2) | VIO | C4 |
| 5 | CLK | DI | MIPI RFFE / SPI Clock | VIO | D4 |
| 6 | CS | DI | Chip Select for SPI | VIO | D3 |
| 7 | DATA | DIO | Digital IO (SPI and MIPI RFFE) | VIO | E4 |
| 8 | VIO | P | Digital IO Supply | 3 | E3 |
| 9 | IDB0 | DI | MIPI RFFE ID Bit 0 (Note 3) | VIO | C2 |
| 10 | GNDIO | P | Digital IO Ground | VIO | D2 |
| 11 | OUTA | AOH | High Voltage Output A | VHV | E2 |
| 12 | OUTB | AOH | High Voltage Output B | VHV | E1 |
| 13 | OUTC | AOH | High Voltage Output C | VHV | D1 |
| 14 | OUTD | AOH | High Voltage Output D | VHV | C1 |
| 15 | OUTE | AOH | High Voltage Output E | VHV | B1 |
| 16 | OUTF | AOH | High Voltage Output F | VHV | A1 |
| 17 | ATEST | AO | Analog Test Out (Note 4) | VREG | B2 |
| 18 | VREG | AO | Regulator Output | 3.6 | A2 |
| 19 | GND_BOOST | P | Ground for Booster | 0 | A3 |
| 20 | VHV | AOH / AIH | Boost High Voltage can be Forced Externally | 25 | A4 |

1. For information only.
2. To be grounded when not in use.
3. This pin has to be connected to either GNDIO or VIO level, even if only SPI protocol is used. Never let it float.
4. To be grounded in normal operation.

Electrical Performance Specifications

Table 2. ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Rating | Unit |
|-------------------------|--|-----------------|------|
| AVDD | Analog Supply Voltage | -0.3 to +6.0 | V |
| VIO | IO Reference Supply Voltage | -0.3 to +3.6 | V |
| V _{I/O} | Input Voltage Logic Lines (DATA, CLK, CS) | -0.3 to VIO+0.3 | V |
| V _{HVH} | VHV Maximum Voltage | -0.3 to 30 | V |
| V _{ESD} (HBM) | Human Body Model, JESD22-A114, All I/O | 2,000 | V |
| V _{ESD} (MM) | Machine Model, JESD22-A115 | 200 | V |
| T _{STG} | Storage Temperature | -55 to +150 | °C |
| T _{AMB_OP_MAX} | Max Operating Ambient Temperature without Damage | +110 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 3. RECOMENDED OPERATING CONDITIONS

| Symbol | Parameter | Rating | | | Unit |
|---------------------|--------------------------------|--------|-----|------|------|
| | | Min | Typ | Max | |
| T _{AMB_OP} | Operating Ambient Temperature | -30 | - | +85 | °C |
| T _{J_OP} | Operating Junction Temperature | -30 | - | +125 | °C |
| AVDD | Analog Supply Voltage | 2.3 | - | 5.5 | V |
| VIO | IO Reference Supply Voltage | 1.1 | - | 3.0 | V |

Table 4. DC CHARACTERISTICS (T_A = -30 to +85°C; V_{OUTX} = 15 V for each output; 2.3 V < AVDD < 5.5 V; 1.1 V < VIO < 3.0 V; R_{LOAD} = equivalent series load of 5.6 kohm and 2.7 nF; C_{HV} = 22 nF; L_{BOOST} = 15 µH; TRIG pin grounded; unless otherwise specified)

| Symbol | Parameter | Min | Typ | Max | Unit | Comment |
|--------|-----------|-----|-----|-----|------|---------|
|--------|-----------|-----|-----|-----|------|---------|

SHUTDOWN MODE

| | | | | | | |
|----------------------|---------------------|----|---|-----|----|-------------------|
| I _{AVDD} | AVDD Supply Current | - | - | 1.5 | µA | VIO Supply is Low |
| I _{L_BOOST} | L_BOOST Leakage | - | - | 1.5 | | |
| I _{BATT} | Battery Current | - | - | 2.5 | | |
| I _{VIO} | VIO Supply Current | -1 | - | 1 | | |
| I _{CLK} | CLK Leakage | -1 | - | 1 | | |
| I _{DATA} | DATA Leakage | -1 | - | 1 | | |

ACTIVE MODE

| | | | | | | |
|---------------------------|---|------|-------|-------|----|--|
| I _{BATT} | Average battery current, 3 outputs actively switching 16 V for 1205 µs to 2 V for 1705 µs to 8 V for 1705 µs and 3 outputs are @ 16 V steady state | - | 1,760 | 2,350 | µA | At VHV = 20 V AVDD = 3.3 V |
| I _{BATT_SS0} | Average battery current, 6 outputs @ 0 V steady state | - | 800 | 1,130 | | At VHV = 20 V AVDD = 3.3 V |
| I _{BAT_SS2} | Average battery current, 6 outputs @ 2 V steady state | - | 850 | 1,200 | µA | At VHV = 20 V AVDD = 3.3 V |
| I _{BATT_SS16} | Average battery current, 6 outputs @ 16 V steady state | - | 1,190 | 1,560 | | At VHV = 20 V AVDD = 3.3 V |
| I _{L_BOOST} | Average inductor current, 3 outputs actively switching 16 V for 1205 µs to 2 V for 1705 µs to 8 V for 1705 µs and 3 outputs are @ 16 V steady state | - | 1,480 | 2,050 | | At VHV = 20 V AVDD = 3.3 V |
| I _{L_BOOST_SS0} | Average inductor current, 6 outputs @ 0 V steady state | - | 500 | 790 | | At VHV = 20 V AVDD = 3.3 V |
| I _{L_BOOST_SS2} | Average inductor current, 6 outputs @ 2 V steady state | - | 560 | 850 | | At VHV = 20 V AVDD = 3.3 V |
| I _{L_BOOST_SS16} | Average inductor current, 6 outputs @ 16 V steady state | - | 930 | 1,270 | | At VHV = 20 V AVDD = 3.3 V |
| I _{VIO_INACT} | VIO average inactive current | - | - | 3 | | VIO is high, no bus activity |
| I _{VIO_ACTIVE} | VIO average active current | - | - | 250 | | VIO = 1.8 V, master sending data at 26 MHz |
| V _{VREG} | | 2.05 | - | 2.3 | V | No external load allowed |

LOW POWER MODE

| | | | | | | |
|----------------------|---------------------|-----|---|-----|----|--|
| I _{AVDD} | AVDD Supply Current | - | - | 8 | µA | |
| I _{L_BOOST} | L_BOOST Leakage | - | - | 6 | | |
| I _{BATT} | Battery Current | - | - | 14 | | I _{AVDD} + I _{L_BOOST} |
| I _{VIO} | VIO Supply Current | - | - | 3 | | No bus activity |
| V _{VREG} | | 2.0 | - | 3.3 | V | No external load allowed |

Table 5. BOOST CONVERTER CHARACTERISTICS(AVDD from 2.3 V to 5.5 V; VIO from 1.1 V to 3.0 V; $T_A = -30$ to $+85^\circ\text{C}$; $C_{HV} = 22$ nF; $L_{BOOST} = 15$ μH ; unless otherwise specified)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------------|---|-------------|-----|-----|-----|------|
| VHV_min | Minimum programmable output voltage (average), DAC Boost = 0h | Active mode | – | 9 | – | V |
| VHV_max | Maximum programmable output voltage (average), DAC Boost = Fh | Active mode | – | 24 | – | |
| Resolution | Boost voltage resolution | 4-bit DAC | – | 1 | – | |
| $I_{L_BOOST_LIMIT}$ | Inductor current limit | | – | 200 | – | mA |

Table 6. ANALOG OUTPUTS (OUT A, OUT B, OUT C)(AVDD from 2.3 V to 5.5 V; VIO from 1.1 V to 3.0 V; VHV = 24 V; $T_A = -30$ to $+85^\circ\text{C}$; $R_{load} = \infty$ unless otherwise specified)

| Parameter | Description | Min | Typ | Max | Unit | Comment |
|-----------|-------------|-----|-----|-----|------|---------|
|-----------|-------------|-----|-----|-----|------|---------|

SHUTDOWN MODE

| | | | | | | |
|-----------|---|---|---|---|---------|--------------|
| Z_{OUT} | OUT A, OUT B, OUT C, OUT D, OUT E, OUT F output impedance | 7 | – | – | megaohm | DAC disabled |
|-----------|---|---|---|---|---------|--------------|

ACTIVE MODE

| | | | | | | |
|--------------|--|------|-----|------|---------------|---|
| V_{OH} | Maximum output voltage | 22.0 | – | – | V | DAC A, B, C, D, E or F = 7Fh, DAC Boost = Fh, $I_{OH} < 10$ μA |
| V_{OL} | Minimum output voltage | – | – | 1 | V | DAC A, B, C, D, E or F = 01h, DAC Boost = 0h to Fh, $I_{OH} < 10$ μA |
| Slew Rate | | – | 6.5 | 10 | μs | 2 V to 20 V step, measured at $V_{OUT} = 15.2$ V, $R_{LOAD} =$ equivalent series load of 2.7 kohm and 5.6 nF, Turbo enabled |
| R_{PD} | OUT A, OUT B, OUT C, OUT D, OUT E, OUT F set in pull-down mode | – | – | 800 | ohm | DAC A, B, C, D, E or F = 00h, DAC Boost = 0h to Fh, selected output(s) is disabled |
| Resolution | Voltage resolution (1-bit) | – | 188 | – | mV | (1 LSB = 1-bit) |
| V_{OFFSET} | Zero scale, least squared best fit | –1 | – | +1 | LSB | |
| Error | | –3.0 | – | +3.0 | % V_{OUT} | Over 2 V – 20 V V_O range |
| DNL | Differential non-linearity least squared best fit | –0.9 | – | +0.9 | LSB | Over 2 V – 20 V V_O range |
| INL | Integral non-linearity least squared best fit | –1 | – | +1 | LSB | Over 2 V – 20 V V_O range |
| I_{SC} | Over current protection | – | 35 | 65 | mA | Any DAC output shorted to ground |
| V_{RIPPLE} | Output ripple with all outputs at steady state | – | – | 40 | mV RMS | Over 2 V – 20 V for VHV = 23.5 V |

Theory of Operation

Overview

The control IC outputs are directly controlled by programming the six DACs (DAC A, DAC B, DAC C, DAC D, DAC E and DAC F) through the digital interface.

The DAC stages are driven from a reference voltage, generating an analog output voltage driving a high-voltage amplifier supplied from the boost converter (see Figure 1 – Control IC Functional Block Diagram).

The control IC output voltages are scaled from 0 V to 24 V, with 128 steps of 188 mV ($2\text{ V} \times 24\text{ V} / 255\text{ V} = 0.188235\text{ V}$). The nominal control IC output can be approximated to $188\text{ mV} \times (\text{DAC value})$.

For performance optimization the boost output voltage (VHV) can be programmed to levels between 9 V and 24 V via the DAC_boost register (4 bits with 1 V steps). The startup default level for the boosted voltage is $\text{VHV} = 24\text{ V}$.

For proper operation and to avoid saturation of the output devices and noise issues it is recommended to operate the boosted VHV voltage at least 2 V above the highest programmed V_{OUT} voltage of any of the six outputs.

When the DAC output value is set to 00h the corresponding output is disabled and the output is pulled to GND through an effective impedance of less than 800 ohms.

Operating Modes

The following operating modes are available:

1. **Shutdown Mode:** All circuit blocks are off, the DAC outputs are disabled and placed in high Z state and current consumption is limited to minimal leakage current. The shutdown mode is entered upon initial application of AVDD or upon VIO being placed in the low state. The contents of the registers are not maintained in shutdown mode.

2. **Startup Mode:** Startup is only a transitory mode. Startup mode is entered upon a VIO high state. In startup mode all registers are reset to their default states, the digital interface is functional, the boost converter is activated, outputs OUT A, OUT B, OUT C, OUT D, OUT E and OUT F are disabled and the DAC outputs are placed in a high Z state. Control software can request a full hardware and register reset of the TCC-106 by sending an appropriate PWR_MODE command to direct the chip from either the active mode or the low power mode to the startup mode. From the startup mode the device automatically proceeds to the active mode.
3. **Active Mode:** All blocks of the TCC-106 are activated and the DAC outputs are fully controlled through the digital interface, DACs remain off until enabled. The DAC settings can be dynamically modified and the HV outputs will be adjusted according to the specified timing diagrams. Each DAC can be individually controlled and/or switched off according to application requirements. Active mode is automatically entered from the startup mode. Active mode can also be entered from the low power mode under control software command.
4. **Low Power Mode:** In low power mode the serial interface stays enabled, the DAC outputs are disabled and are placed in a high Z state and the boost voltage circuit is disabled. Control software can request to enter the low power mode from the active mode by sending an appropriate PWR_MODE command. The contents of all registers are maintained in the low power mode.

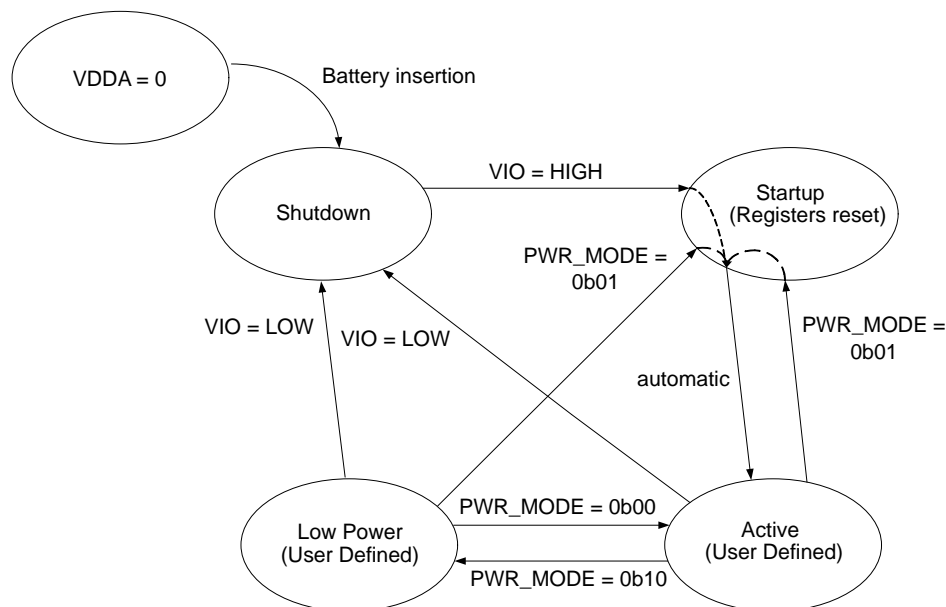


Figure 2. Modes of Operation

AVDD Power-On Reset (POR)

Upon application of AVDD the TCC-106 will be in shutdown mode. All circuit blocks are off and the chip draws only minimal leakage current.

VIO Power-On Reset and Startup Conditions

A high level on VIO places the chip in startup mode which provides a POR to the TCC-106. POR resets all registers to their default settings as described in Table 8. VIO POR also resets the serial interface circuitry. POR is not a brown-out detector and VIO needs to be brought back to a low level to enable the POR to trigger again.

Table 7. VIO POWER-ON RESET AND STARTUP

| Register | Default State for VIO POR | Comment |
|------------|---------------------------|--|
| DAC Boost | [1111] | VHV = 24 V |
| Power Mode | [01]>[00] | Transitions from shutdown to startup and then automatically to active mode |
| DAC Enable | [000000] | V _{OUT} A, B, C, D, E and F Disabled |
| DAC A | | Output in High-Z Mode |
| DAC B | | Output in High-Z Mode |
| DAC C | | Output in High-Z Mode |
| DAC D | | Output in High-Z Mode |
| DAC E | | Output in High-Z Mode |
| DAC F | | Output in High-Z Mode |

VIO Shutdown

A low level at any time on VIO places the chip in shutdown mode in which all circuit blocks are off. The contents of the registers are not maintained in shutdown mode.

Table 8. VIO THRESHOLDS (AVDD from 2.3 V to 5.5 V; T_A = -30 to +85°C unless otherwise specified)

| Parameter | Description | Min | Typ | Max | Unit | Comments |
|-----------|-------------------|-----|-----|-----|------|---|
| VIORST | VIO Low Threshold | – | – | 0.2 | V | When VIO is lowered below this threshold level the chip is reset and placed into the shutdown state |

Power Supply Sequencing

The AVDD input is typically directly supplied from the battery and thus is the first on. After AVDD is applied and before VIO is applied to the chip, all circuits are in the shutdown state and draw minimum leakage currents. Upon application of VIO, the chip automatically starts up using default settings and is placed in the active state waiting for a command via the serial interface.

Table 9. TIMING (AVDD from 2.3 V to 5.5 V; VIO from 1.1 V to 3.0 V; T_A = -30 to +85°C; OUT A, OUT B, OUT C, OUT D, OUT E & OUT F; CHV = 22 nF; L_{BOOST} = 15 µH; VHV = 20 V; Turbo-Charge mode off unless otherwise specified)

| Parameter | Description | Min | Typ | Max | Unit | Comments |
|--------------------------|--|-----|-----|-----|------|--|
| T _{POR_VREG} | Internal bias settling time from shutdown to active mode | – | 50 | 120 | µs | For info only |
| T _{BOOST_START} | Time to charge CHV @ 95% of set VHV | – | 130 | – | µs | For info only |
| T _{SD=TO=ACT} | Startup time from shutdown to active mode | – | 180 | 300 | µs | |
| T _{SET+} | Output A, B, C, D, E, F positive settling time to within 5% of the delta voltage, equivalent series load of 2.7 kohm and 5.6 nF, V _{OUT} from 2 V to 20 V; 0Bh (11d) to 55h (85d) | – | 50 | 60 | µs | Voltage settling time connected on V _{OUT} A, B, C, D, E, F |
| T _{SET–} | Output A, B, C, D, E, F negative settling time to within 5% of the delta voltage, equivalent series load of 2.7 kohm and 5.6 nF, V _{OUT} from 20 V to 2 V; 55h (85d) to 0Bh (11d) | – | 50 | 60 | µs | Voltage settling time connected on V _{OUT} A, B, C, D, E, F |
| T _{SET+} | Output A, B, C, D, E, F positive settling time with Turbo | – | 35 | – | µs | Voltage settling time connected on V _{OUT} A, B, C, D, E, F |
| T _{SET–} | Output A, B, C, D, E, F negative settling time with Turbo | – | 35 | – | µs | Voltage settling time connected on V _{OUT} A, B, C, D, E, F |

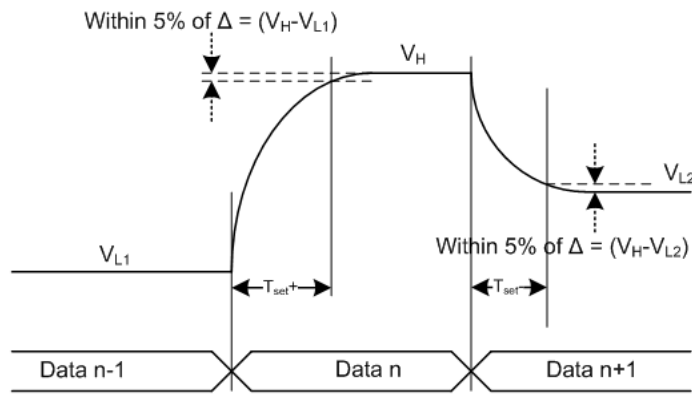


Figure 3. Output Settling Diagram

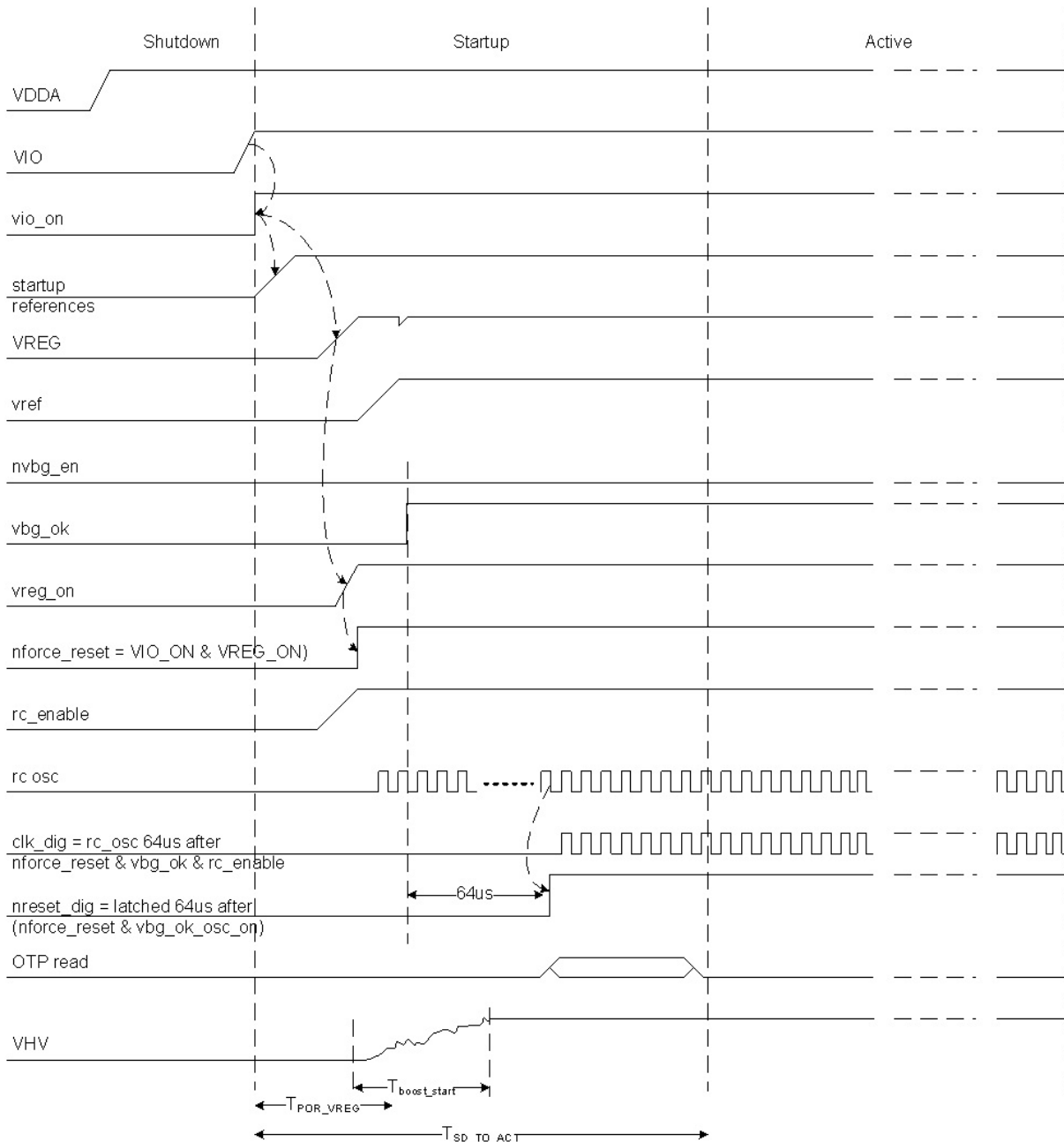


Figure 4. Startup Timing Diagram

Boost Control

The TCC-106 integrates an asynchronous current control boost converter. It operates in a discontinuous mode and features spread-spectrum circuitry for Electro-Magnetic Interference (EMI) reduction. The average boost clock is 2 MHz and the clock is spread between 0.8 MHz and 3.2 MHz.

Boost Output Voltage (VHV) Control Principle

The asynchronous control starts the boost converter as soon as the VHV voltage drops below the reference set by the 4-bit DAC and stops the boost converter when the VHV voltage rises above the reference again.

Due to the slow response time of the control loop, the VHV voltage may drop below the set voltage before the control loop compensates for it. In the same manner, VHV can rise higher than the set value. This effect may reduce the maximum output voltage available. Please refer to Figure 6 below.

The asynchronous control reduces switching losses and improves the output (VHV) regulation of the DC/DC converter under light load, particularly in the situation where the TCC-106 only maintains the output voltages to fixed values.

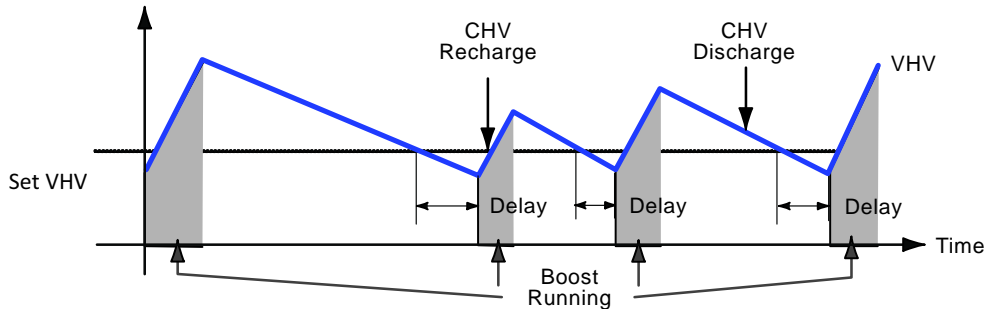


Figure 5. VHV Voltage Waveform

High Impedance (High Z) Feature

In shutdown mode the OUT pins are set to a high impedance mode (high Z). Following is the principle of operation for the control IC:

1. The DAC output voltage V_{OUT} is defined by:

$$V_{OUT} = \frac{\text{DAC code}}{255} \times 24 \text{ V} \times 2 \quad (\text{eq. 1})$$

2. The voltage VHV defines the maximum supply voltage of the DAC supply output regulator and is set by a 4-bit control.
3. The maximum DAC DC output voltage V_{OUT} is limited to $(VHV - 2 \text{ V})$.
4. The minimum output DAC voltage V_{OUT} is 1.0 V max.

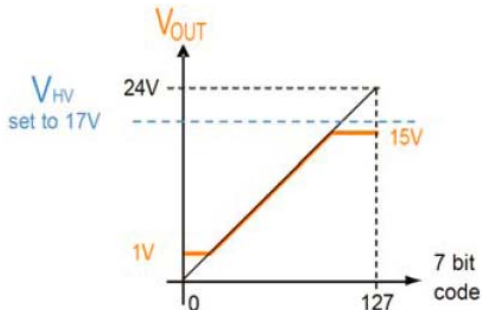


Figure 6. DAC Output Range Example A

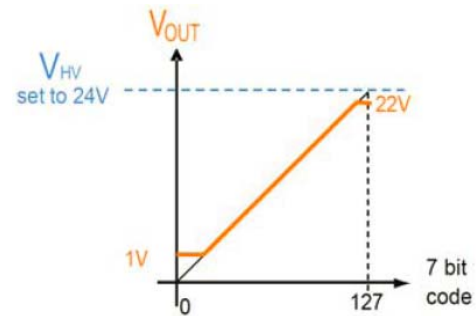


Figure 7. DAC Output Range Example B

Digital Interface

The control IC is fully controlled through a digital interface (DATA, CLK, CS). The digital interface automatically detects and responds to MIPI RFFE interface commands, 3-wire 30-bit serial interface commands or 3-wire 32-bit serial interface commands. Auto-detection is accomplished on a frame by frame basis. The digital interface is described in the following sections of this document, for detailed programming instructions please refer to the programming guide, available by contacting ON Semiconductor.

3-Wire Serial Interface

The 3-wire serial interface operates in a synchronous write-only 3-wire slave mode. 30-bit or 32-bit message length is automatically detected for each frame. If CS changes state before all bits are received then all data bits are ignored. Data is transmitted most significant bit first and DATA is latched on the rising edge of CLK. Commands are latched on the falling edge of CS.

Table 10. 3-WIRE SERIAL INTERFACE SPECIFICATION(T_A = -30 to +85°C; 2.3 V < AVDD < 5.5 V; 1.1 V < VIO < 3.0 V; unless otherwise specified)

| Parameter | Description | Min | Typ | Max | Unit | Comments |
|------------------------|---|-----------|-------|-----------|------|--|
| F _{CLK} | Clock Frequency | – | – | 26 | MHz | |
| T _{CLK} | Clock Period | 38.4 | – | – | ns | |
| N _{BIT} | Bits Number | – | 30/32 | – | bits | Auto-detection 30-bit or 32-bit |
| T _{HIGH} | Clock High Time | 13 | – | – | ns | |
| T _{LOW} | Clock Low Time | 13 | – | – | ns | |
| TCS _{SETUP} | CS Set-up Time | 5 | – | – | ns | 70% rising edge of CS to 30% rising edge of first clock cycle |
| TCS _{HOLD} | CS Hold Time | 5 | – | – | ns | 30% falling edge of last clock cycle to 70% falling edge of CS |
| TD _{SETUP} | Data Set-up Time | 4 | – | – | ns | Relative to 30% of CLK rising edge |
| TD _{HOLD} | Data Hold Time | 4 | – | – | ns | relative to 70% of CLK rising edge |
| T _{SUCC} | CS Low Time Between Successive Writes | 38.4 | – | – | ns | 70% falling edge of CS to 70% rising edge of CS |
| T _{SUCC} | CS Low Time Between Successive DAC Update Writes | 1,500 | – | – | ns | Time between groups of DAC update reg [00000] & [00001] writes |
| C _{CLK} | Input Capacitance | – | – | 5 | pF | CLK pin |
| C _{DATA} | Input Capacitance | – | – | 8.3 | pF | DATA pin |
| C _{CS} | Input Capacitance | – | – | 5 | pF | CS pin |
| C _{TRIG} | Input Capacitance | – | – | 10 | pF | TRIG pin |
| V _{IH} | Input Logic Level High | 0.7 x VIO | – | VIO + 0.3 | V | DATA, CLK, CS |
| V _{IL} | Input Logic Level Low | –0.3 | – | 0.3 x VIO | V | DATA, CLK, CS |
| I _{IH_DATA} | Input Current High | –2 | – | 10 | μA | DATA |
| I _{IL_DATA} | Input Current Low | –2 | – | 1 | μA | DATA |
| I _{IH_CLK,CS} | Input Current High | –1 | – | 10 | μA | CLK, CS |
| I _{IL_CLK,CS} | Input Current Low | –1 | – | 1 | μA | CLK, CS |
| V _{TP_TRIG} | Positive Going Threshold Voltage | 0.4 x VIO | – | 0.7 x VIO | V | TRIG |
| V _{TN_TRIG} | Negative Going Threshold Voltage | 0.3 x VIO | – | 0.6 x VIO | V | TRIG |
| V _{H_TRIG} | Hysteresis Voltage (V _{TP} – V _{TN}) | 0.1 x VIO | – | 0.4 x VIO | V | TRIG |
| I _{IH_TRIG} | TRIG Input Current High | –2 | – | 10 | μA | TRIG=0.8 x VIO |
| I _{IL_TRIG} | TRIG Input Current Low | –2 | – | 1 | μA | TRIG=0.2 x VIO |

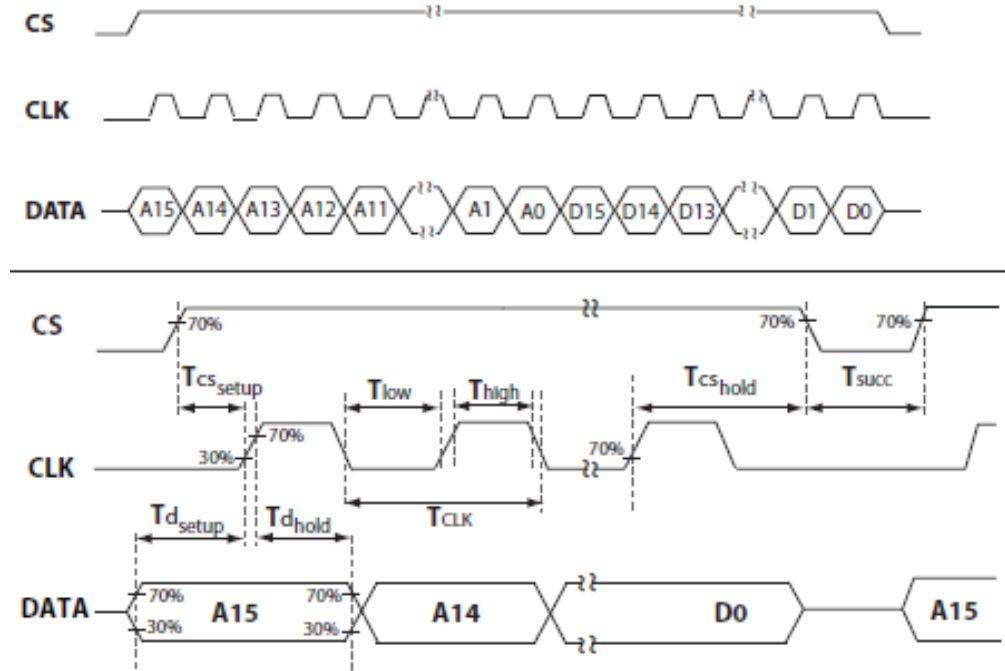


Figure 8. 3-wire Serial Interface Signal Timing

SPI Frame Length Decoding

30-bit or 32-bit frame length is automatically detected. The length of the frame is defined by the number of clock

rising edges while CS is kept high. The TCC-106 will not respond to a SPI command if the length of the frame is not exactly 30 bits or 32 bits. SPI registers are write only.

SPI Frame Structure**Table 11. 32 BITS FRAME: ADDRESS DECODING (1, 2, 3, 4, 5 or 6 OUTPUTS)**

| H0 | H1 | R/W | A12 | A11 | A10 | A9 | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 |
|-------------------------|----|-----|-----|-----------|-----|----|--------------------|----|----|----|--------------------------------|----|----|----|----|
| 1 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | X | X | X | X | X |
| ON Semiconductor Header | | | R/W | Device ID | | | Specific Device ID | | | | Register Address for Operation | | | | |

Table 12. 30 BITS FRAME: ADDRESS DECODING (1, 2, 3, 4, 5 or 6 OUTPUTS)

| R/W | A12 | A11 | A10 | A9 | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 |
|-----|-----------|-----|-----|--------------------|----|----|----|--------------------------------|----|----|----|----|----|
| 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | X | X | X | X | X |
| R/W | Device ID | | | Specific Device ID | | | | Register Address for Operation | | | | | |

Table 13. 3-WIRE SERIAL INTERFACE ADDRESS MAP

| A4 | A3 | A2 | A1 | A0 | Data[15:8] | Data[7:0] |
|----|----|----|----|----|---|--|
| 0 | 0 | 0 | 0 | 0 | Turbo-Charge Settings for DAC A, B, C | DAC C |
| 0 | 0 | 0 | 0 | 1 | DAC B | DAC A |
| 0 | 0 | 0 | 1 | 0 | Turbo-Charge Settings for DAC D, E, F | DAC F |
| 0 | 0 | 0 | 1 | 1 | DAC E | DAC D |
| 0 | 0 | 1 | 0 | 0 | Turbo-Charge Delay Parameters for DAC A, B, C | Turbo Threshold Delay Settings for A, B, C |
| 0 | 0 | 1 | 0 | 1 | Turbo-Charge Delay Parameters for DAC D, E, F | Turbo Threshold Delay Settings for A, B, C |
| 1 | 0 | 0 | 0 | 0 | Mode Select + Control IC Setup | |

Table 13. 3-WIRE SERIAL INTERFACE ADDRESS MAP

| | | | | | | |
|----|---|---|---|---|----------|----------|
| 1 | 0 | 0 | 1 | 0 | Reserved | Reserved |
| to | | | | | | |
| 1 | 1 | 1 | 1 | 1 | | |

Turbo-Charge Mode

The TCC-106 control IC has a Turbo-Charge mode that significantly shortens the system settling time when changing programming voltages. In Turbo-Charge mode the DAC output target voltage is temporarily set to either a delta voltage above or a delta voltage below the actual desired target for the TCDLY time. It is recommended that V_{HV} be set to 24 V when using Turbo-Charge mode.

Glide Mode

Unlike turbo mode, which is intended to reduce the charging time, the glide mode extends the transition time of each DAC output. Each DAC has an individual control for turbo mode, glide mode or regular voltage switching. The glide mode can be enabled for a particular DAC through the INDEX register, by setting DAC State to '1' when glide mode is enabled, turbo mode is off for a particular DAC, but one DAC can be gliding while the other is turbo.

During glide mode the output voltage of a DAC is either increased or decreased to its set end point, in max 255 steps, where each DAC time step can be programmed between 2 μ s to 64 μ s. For programming the glide mode refer to the application note (coming soon). A programming input is not required to maintain a glide transition, all step controls are maintained by the part. Only the inputs to define the glide need to be programmed.

RF Front-End Control Interface (MIPI RFFE Interface)

The TCC-106 is a read/write slave device which is fully compliant to the MIPI Alliance Specification for RF Front-End Control Interface (RFFE) Version 1.10.00 26 July 2011. This device is rated at full-speed operation for 1.65 V < V_{IO} < 1.95 V and at half-speed operation for 1.1 V < V_{IO} < 1.65 V. When using the MIPI RFFE interface the CS pin must be grounded externally.

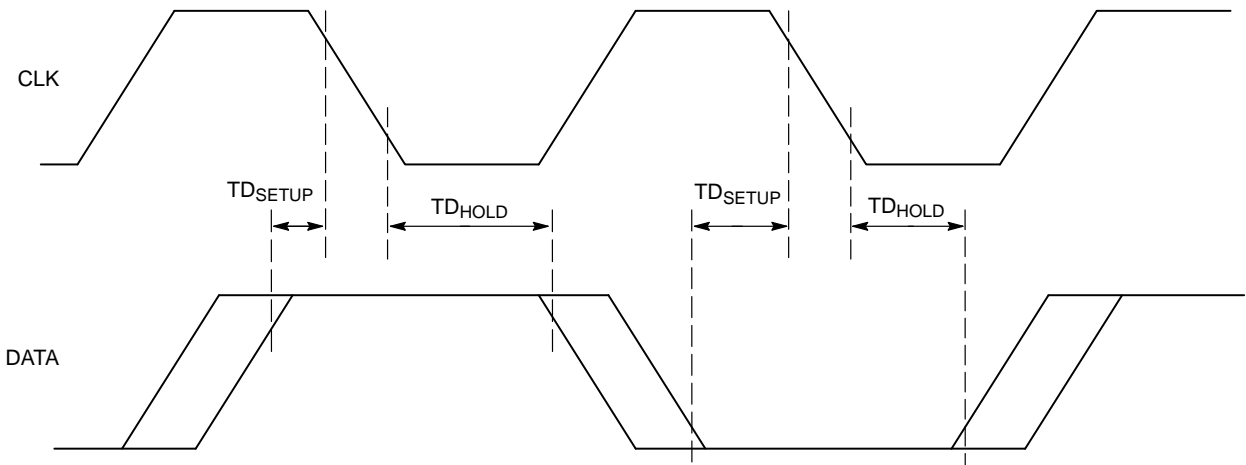
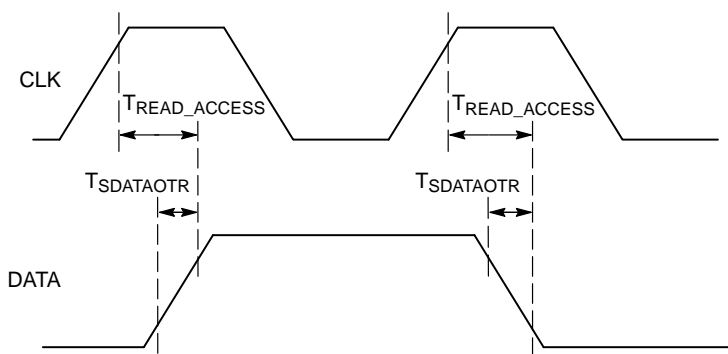
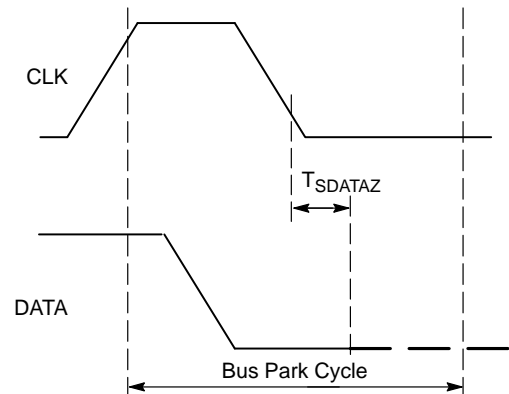
**Figure 9. MIPI-RFFE Signal Timing during Master Writes to PTIC Control IC****Figure 10. MIPI-RFFE Signal Timing during Master Reads from PTIC Control IC****Figure 11. Bus Park Cycle Timing when MIPI-RFFE Master Reads from PTIC Control IC**

Table 14. MIPI RFFE INTERFACE SPECIFICATION(T_A = -30 to +85°C; 2.3 V < AVDD < 5.5 V; 1.1 V < VIO < 1.95 V; unless otherwise specified)

| Parameter | Description | Min | Typ | Max | Unit | Comments |
|--------------------------|---|-----------|-----|-----------|------|--|
| F _{SCLK} | Clock Full-Speed Frequency | 0.032 | – | 26 | MHz | Full-Speed Operation: 1.65 V < VIO < 1.95 V |
| T _{SCLK} | Clock Full-Speed Period | 0.038 | – | 32 | μs | Full-Speed Operation: 1.65 V < VIO < 1.95 V |
| T _{SCLKIH} | CLK Input High Time | 11.25 | – | – | ns | Full-Speed |
| T _{SCLKIL} | CLK Input Low Time | 11.25 | – | – | ns | Full-Speed |
| F _{SCLK_HALF} | Clock Half-Speed Frequency | 0.032 | – | 13 | MHz | |
| T _{SCLK_HALF} | Clock Half-Speed Period | 0.038 | – | 64 | μs | |
| T _{SCLKIH} | CLK Input High Time | 24 | – | – | ns | Half-Speed |
| T _{SCLKIL} | CLK Input Low Time | 24 | – | – | ns | Half-Speed |
| V _{TP} | Positive Going Threshold Voltage | 0.4 x VIO | – | 0.7 x VIO | V | CLK, DATA, TRIG, 1.2 or 1.8 V Bus |
| V _{TN} | Negative Going Threshold Voltage | 0.3 x VIO | – | 0.6 x VIO | V | CLK, DATA, TRIG, 1.2 or 1.8 V Bus |
| V _H | Hysteresis Voltage (V _{TP} – V _{TN}) | 0.1 x VIO | – | 0.4 x VIO | V | CLK, DATA, TRIG, 1.2 or 1.8 V Bus |
| I _{IH} | Input Current High | –2 | – | +10 | μA | TRIG, SDATA = 0.8 x VIO |
| | | –1 | – | +10 | μA | SCLK = 0.8 x VIO |
| I _{IL} | Input Current Low | –2 | – | +1 | μA | TRIG, SDATA = 0.2 x VIO |
| | | –1 | – | +1 | μA | SCLK = 0.2 x VIO |
| C _{CLK} | Input Capacitance | – | – | 5 | pF | CLK Pin |
| C _{DATA} | Input Capacitance | – | – | 8.3 | pF | DATA Pin |
| C _{TRIG} | Input Capacitance | – | – | 10 | pF | TRIG Pin |
| TD _{SETUP} | Write DATA Setup Time | 1 | – | – | ns | Full-Speed |
| TD _{HOLD} | Write DATA Hold Time | 5 | – | – | ns | Full-Speed |
| TD _{SETUP} | Write DATA Setup Time | 2 | – | – | ns | Half-Speed |
| TD _{HOLD} | Write DATA Hold Time | 5 | – | – | ns | Half-Speed |
| T _{SUCC} | Time Between Successive DAC Update Writes | 1,500 | – | – | ns | |
| T _{READ_ACCESS} | Read DATA valid from CLK rising edge | – | – | 100 | ns | Full or Half Speed at VIO = 1.10 V, and max 15 pF load on DATA pin |
| T _{SDATAOTR} | Read DATA output transition | – | – | 65 | ns | Full or Half Speed at VIO = 1.10 V, and max 15 pF load on DATA pin |
| T _{SDATAZ} | Read DATA drive release time | – | – | 180 | ns | Full or Half Speed at VIO = 1.10 V, and max 15 pF load on DATA pin |
| T _{READ_ACCESS} | Read DATA valid from CLK rising edge | – | – | 31 | ns | Full or Half Speed at VIO = 1.80 V, and max 15 pF load on DATA pin |
| T _{SDATAOTR} | Read DATA output transition | – | – | 14 | ns | Full or Half Speed at VIO = 1.80 V, and max 15 pF load on DATA pin |
| T _{SDATAZ} | Read DATA drive release time | – | – | 50 | ns | Full or Half Speed at VIO = 1.80 V, and max 15 pF load on DATA pin |

The control IC contains twenty-four 8-bit registers. Register content is described in Table 15. Some additional registers implemented as provision, are not described in this document.

Table 15. MIPI RFFE ADDRESS MAP

| Register Address | Description | Purpose | Access Type | Size (bits) |
|------------------|---|---|-------------|-------------|
| 0x00 | DAC Configuration (Enable Mask) | High voltage output enable mask | Write | 7 |
| 0x01 | Turbo Register DAC A, B & C | Turbo-charge configuration DAC A, B & C | Write | 8 |
| 0x02 | DAC A Register | OUT A value [6:0], Turbo Index [7]** | Write | 8 |
| 0x03 | DAC B Register | OUT B value [6:0], Turbo Index [7]** | Write | 8 |
| 0x04 | DAC C Register | OUT C value [6:0], Turbo Index [7]** | Write | 8 |
| 0x05 | Turbo Register DAC D, E & F | Turbo-charge configuration DAC D,E & F | Write | 8 |
| 0x06 | DAC D Register | OUT D value [6:0], Turbo Index [7]** | Write | 8 |
| 0x07 | DAC E Register | OUT E value [6:0], Turbo Index [7]** | Write | 8 |
| 0x08 | DAC F Register | OUT F value [6:0], Turbo Index [7]** | Write | 8 |
| 0x10 | DAC Boost (VHV) | Settings for the boost high voltage | Write | 8 |
| 0x11 | Trigger register | Trigger configuration | Write | 8 |
| 0x12 | Turbo-Charge Delay DAC A, B, C | Turbo-charge delay steps DAC A, B, C | Write | 8 |
| 0x13 | Turbo-Charge Delay DAC A, B, C | Turbo-charge delay, multiplication DAC A, B, C | Write | 8 |
| 0x14 | Turbo-Charge Delay DAC D, E, F | Turbo-charge delay steps DAC D, E, F | Write | 8 |
| 0x15 | Turbo-Charge Delay DAC D, E, F | Turbo-charge delay multiplication DAC D, E, F | Write | 8 |
| 0x1C | Power Mode and Trigger Register | Power mode & trigger control PWR_MODE [7:6] TRIG_REG [5:0] | Write | 8 |
| 0x1D | Product ID Register | Product number * Hard coded into ASIC | Write | 8 |
| 0x1E | Manufacturer ID Register | MN (10 bits long) Manufacturer ID[7:0] Hard Coded into ASIC | Write | 8 |
| 0x1F | Unique Slave Identifier Register (USID) | Spare [7:6] [5,4] = Manufacturer ID [9:8] USID [3:0] | Write | 8 |

*The second least significant bit can be programmed in OTP during manufacture

** The details for configuration of Turbo mode should be ascertained from the Programming Guide, available from ON Semiconductor

Configuration Settings

Table 16. DAC CONFIGURATION (ENABLE MASK) at [0x00] Defaults shown as (x)

| Bit 6 (1) | Bit 5 (0) | Bit 4 (0) | Bit 3 (0) | Bit 2 (0) | Bit 1 (0) | Bit 0 (0) |
|-----------|-----------|-----------|-----------|-----------|-----------|-----------|
| SSE | DAC E | DAC F | DAC A | DAC B | DAC C | DAC D |

SSE = 0 spread spectrum disabled, SSE = 1 spread spectrum enabled (default), this controls the average boost clock which is nominally 2 MHz and spread between 0.8 MHz and 3.2 MHz when enabled (default). The hardware does not limit driving more than three DACs at the same time, however it is recommended to have max three DACs changing outputs at one time, no restrictions exist as to which three.

Table 17. DAC MODE SETUP: DAC ENABLE

| Bit3 | Bit2 | Bit1 | DAC A | DAC B | DAC C | |
|------|------|------|---------|---------|---------|-----------|
| 0 | 0 | 0 | Off | Off | Off | (Default) |
| 0 | 0 | 1 | Off | Off | Enabled | |
| 0 | 1 | 0 | Off | Enabled | Off | |
| 0 | 1 | 1 | Off | Enabled | Enabled | |
| 1 | 0 | 0 | Enabled | Off | Off | |
| 1 | 0 | 1 | Enabled | Off | Enabled | |
| 1 | 1 | 0 | Enabled | Enabled | Off | |
| 1 | 1 | 1 | Enabled | Enabled | Enabled | |

Table 18. DAC MODE SETUP: DAC ENABLE

| Bit5 | Bit4 | Bit0 | DAC E | DAC F | DAC D | |
|------|------|------|---------|---------|---------|-----------|
| 0 | 0 | 0 | Off | Off | Off | (Default) |
| 0 | 0 | 1 | Off | Off | Enabled | |
| 0 | 1 | 0 | Off | Enabled | Off | |
| 0 | 1 | 1 | Off | Enabled | Enabled | |
| 1 | 0 | 0 | Enabled | Off | Off | |
| 1 | 0 | 1 | Enabled | Off | Enabled | |
| 1 | 1 | 0 | Enabled | Enabled | Off | |
| 1 | 1 | 1 | Enabled | Enabled | Enabled | |

Table 19. BOOST DAC MODE SETUP (VHV) at [0x10] (Note 5)

| Bit 7* | Bit 6* | Bit 5* | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 | VHV (V) |
|--------|--------|--------|-------|-------|-------|-------|-------|--------------|
| 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 9 |
| 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 10 |
| 0 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 11 |
| 0 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 12 |
| 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 13 |
| 0 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 14 |
| 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 15 |
| 0 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 16 |
| 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 17 |
| 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 18 |
| 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 19 |
| 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 20 |
| 0 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 21 |
| 0 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 22 |
| 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 23 |
| 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 24 (Default) |

5. Bit 4 is fixed at logic 1 for reverse software compatibility

*Indicates reserved bits

MIPI RFFE TRIG Operation

The MIPI RFFE Trigger mode can be used as a synchronization signal to ensure that new DAC settings are applied to the outputs at appropriate times in the overall transceiver system. When the MIPI RFFE TRIG function is enabled via [0x11] bit 4 the requested DAC voltage levels are set up in the shadow registers and not transferred to the destination registers until the trigger condition is met. In this manner the change in output voltage levels are synchronized with the MIPI RFFE TRIG command. If multiple DAC voltage level requests are received before the TRIG event occurs, only the last fully received DAC output voltage level will be applied to the outputs.

The trigger configuration also provides for an additional external TRIG pin to be used as a synchronization signal. The external TRIG is independent from the built-in triggers available within the MIPI RFFE interface. When the TRIG input pin is enabled via [0x11] bit 4 the requested DAC voltage levels are set up in the shadow registers and are not transferred to the destination registers until the external trigger condition is met. In this manner the change in output voltage levels are synchronized with the external TRIG event. The external TRIG input is referenced to VIO. To

improve interfacing options the polarity of external TRIG is programmable via [0x11] bit 1.

If the external trigger function is not needed in the application, the TRIG pin should be grounded and the TRIG function disabled. When TRIG pin is disabled by register [0x11] 'TRIG Select' = '1' (default) and register [0x10] 'Trigger Mask 0, 1, 2' = '1':

- The requested DAC voltage levels for DAC A, B, C are applied to the outputs all together at the same time, after DAC C value is written. This event will not affect the outputs of DAC D, E, F.
- The requested DAC voltage levels for DAC D, E, F are applied to the outputs all together at the same time, after DAC F value is written. This event will not affect the outputs of DAC A, B, C.
- Optionally a configuration register can select the last DAC to be written in order to trigger internally the update of all six DACs at the same time. For example the configuration register can select that a write to DAC B value will trigger internally the update of all six DACs outputs.

Table 20. TRIGGER CONFIGURATION at [0x11]

| Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|-----------|-----------|-----------|---|---------------|-------|--|------------------------------------|
| Res* 0 | Res* 0 | Res* 0 | TRIG Select 0 = Ext TRIG Pin 1 = RFFE Trigger | Reserved 0 | | TRIG Edge 0 = Active Falling 1 = Active Rising | Mask Ext TRIG 1 = Mask Trig Pin |

*Reserved bits

Table 21. EXTERNAL TRIGGER CONFIGURATION BIT SETTING AT [0x11]

| Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 | Description |
|-------|-------|-------|-------|-------|--|
| 0 | – | – | X | 0 | External trigger pin is enabled. Sending the RFFE message will load a 'shadow' register only. Only upon an active signal on external TRIG pin are the output registers loaded with the new voltage settings which are then applied to the outputs. |
| 1 | – | – | X | X | The MIPI RFFE trigger is enabled (Default) |
| 0 | – | – | 0 | 0 | External TRIG pin signal is active falling |
| 0 | – | – | 1 | 0 | External TRIG pin signal is active rising (Default) |
| X | – | – | X | 0 | External trigger pin is not masked |
| X | – | – | X | 1 | Mask external trigger pin (Default) |

Table 22. POWER MODE AND TRIGGER REGISTER [0x1C]

| Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|-------|-------|----------------|----------------|----------------|-----------|-----------|-----------|
| PM1 | PM0 | Trigger Mask 2 | Trigger Mask 1 | Trigger Mask 0 | Trigger 2 | Trigger 1 | Trigger 0 |

Writing a logic one ('1') to the bits 0, 1 or 2 (Trigger 0, 1 or 2) moves data from the shadow registers into the destination registers. Default for bit 0, 1 and 2 is logic low.

If trigger mask bit 0, 1 or 2 is set ('1') the trigger 0, 1 or 2 are disabled respectively and the data goes directly to the destination register. Default for bit 3, 4 and 5 is logic low.

All three triggers behave in the same way as the external pin TRIG. When each of these triggers is set using the MIPI RFFE interface the results are the same as when an active edge is applied to the TRIG pin when external pin TRIG is selected

Table 23. POWER MODE BIT SETTING IN REGISTER [0x1C]

| PM1 | PM0 | State | Description |
|-----|-----|-----------|---|
| 0 | 0 | Active | Boost Control Active, VHV set by Digital Interface V _{OUT} A, B, C, D, E, F Enabled and Controlled by Digital Interface (Default) |
| 0 | 1 | Startup | Boost Control Active, VHV set by Digital Interface V _{OUT} A, B, C, D, E, F Disabled |
| 1 | 0 | Low Power | Digital Interface is Active While All Other Circuits are in Low Power Mode |
| 1 | 1 | Reserved | State of Hardware Does Not Change |

Command Sequences

- **Register 0 Write** (used to access the Register 0 DAC Configuration – Enable Mask). Register 0 can be also be accessed using Register Write or/and Extended Register Write.
- **Register Write** (used to access only one register at the time)
- **Extended Register Write** (used to access a group of contiguous registers with one command)

Register 0 Write Command Sequence

The Command Sequence starts with a Sequence Start Condition (SSC) which is followed by the Register 0 Write Command Frame. This Frame contains the Slave address, a logic one, and the seven bit word that will be written to Register 0. The Command Sequence is depicted below.

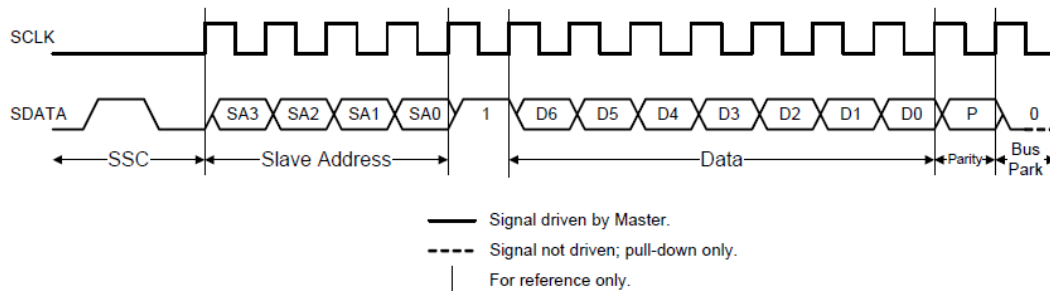


Figure 12. Register 0 Write Command Sequence

Table 24. MIPI RFFE COMMAND FRAME FOR REGISTER 0 WRITE COMMAND SEQUENCE

| Description | SSC | | Command Frame | | | | | | | | | | BP |
|-------------------------|-----|---|---------------|---|-----|-------|-------|-------|-------|-------|-------|---|----|
| SSE & DAC Configuration | 1 | 0 | SA [3,0] | 1 | SSE | DAC_E | DAC_F | DAC_A | DAC_B | DAC_C | DAC_D | P | BP |

Register Write Command Sequence

The write register command sequence may be used to access each register (addresses 0–31).

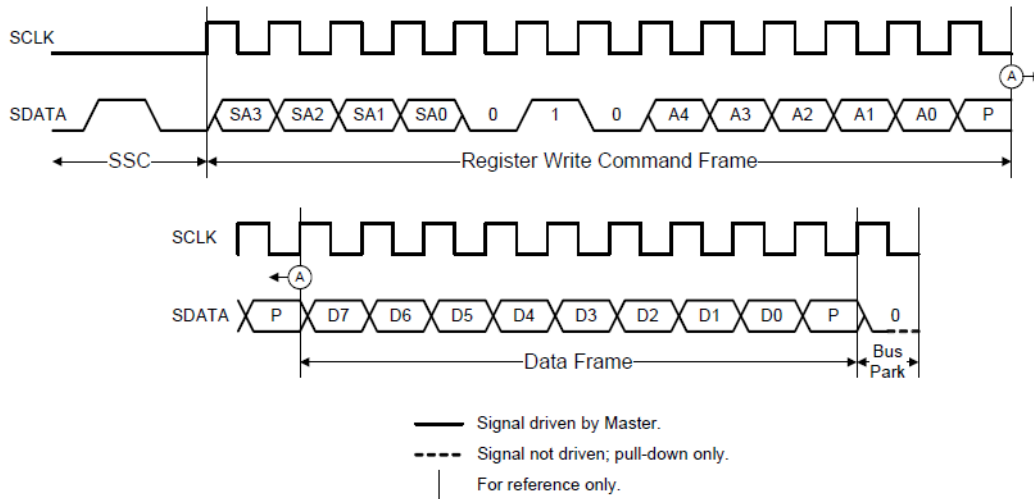


Figure 13. Register Write Command Sequence

Table 25. MIPI RFFE COMMAND FRAME FOR REGISTER WRITE COMMAND SENTENCE

| Description | SSC | | Command Frame | | | | | | | | | | Data Frame | | BP |
|-----------------------|-----|---|---------------|---|---|---|---|---|---|---|---|---|-------------------------------|--|----|
| Turbo-Charge Settings | 1 | 0 | SA [3,0] | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | P | TC_IND_X_L [7:0] | | BP |
| Register Write DAC A | 1 | 0 | SA [3,0] | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | P | TC_IND_X_L [8] & DAC_A [6:0] | | BP |
| Register Write DAC B | 1 | 0 | SA [3,0] | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | P | TC_IND_X_L [9] & DAC_B [6:0] | | BP |
| Register Write DAC C | 1 | 0 | SA [3,0] | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | P | TC_IND_X_L [10] & DAC_C [6:0] | | BP |

Table 26. MIPI RFFE COMMAND FRAME FOR REGISTER WRITE COMMAND SENTENCE

| Description | SSC | | Command Frame | | | | | | | | | | Data Frame | | BP |
|-----------------------|-----|---|---------------|---|---|---|---|---|---|---|---|---|-------------------------------|--|----|
| Turbo-Charge Settings | 1 | 0 | SA [3,0] | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | P | TC_IND_X_U [7:0] | | BP |
| Register Write DAC D | 1 | 0 | SA [3,0] | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | P | TC_IND_X_U [8] & DAC_D [6:0] | | BP |
| Register Write DAC E | 1 | 0 | SA [3,0] | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | P | TC_IND_X_U [9] & DAC_E [6:0] | | BP |
| Register Write DAC F | 1 | 0 | SA [3,0] | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | P | TC_IND_X_U [10] & DAC_F [6:0] | | BP |

Extended Register Write Command Sequence

In order to access more than one register in one sequence this message could be used. Most commonly it will be used for loading three DAC registers at the same time. The four LSBs of the extended register write command frame determine the number of bytes that will be written by the command sequence. A value of 0b0000 would write one byte and a value of 0b1111 would write 16 bytes.

If more than one byte is to be written, the register address in the command sequence contains the address of the first extended register that will be written to and the slave's local extended register address shall be automatically incremented by one for each byte written up to address 0x1F, starting from the address indicated in the address frame.

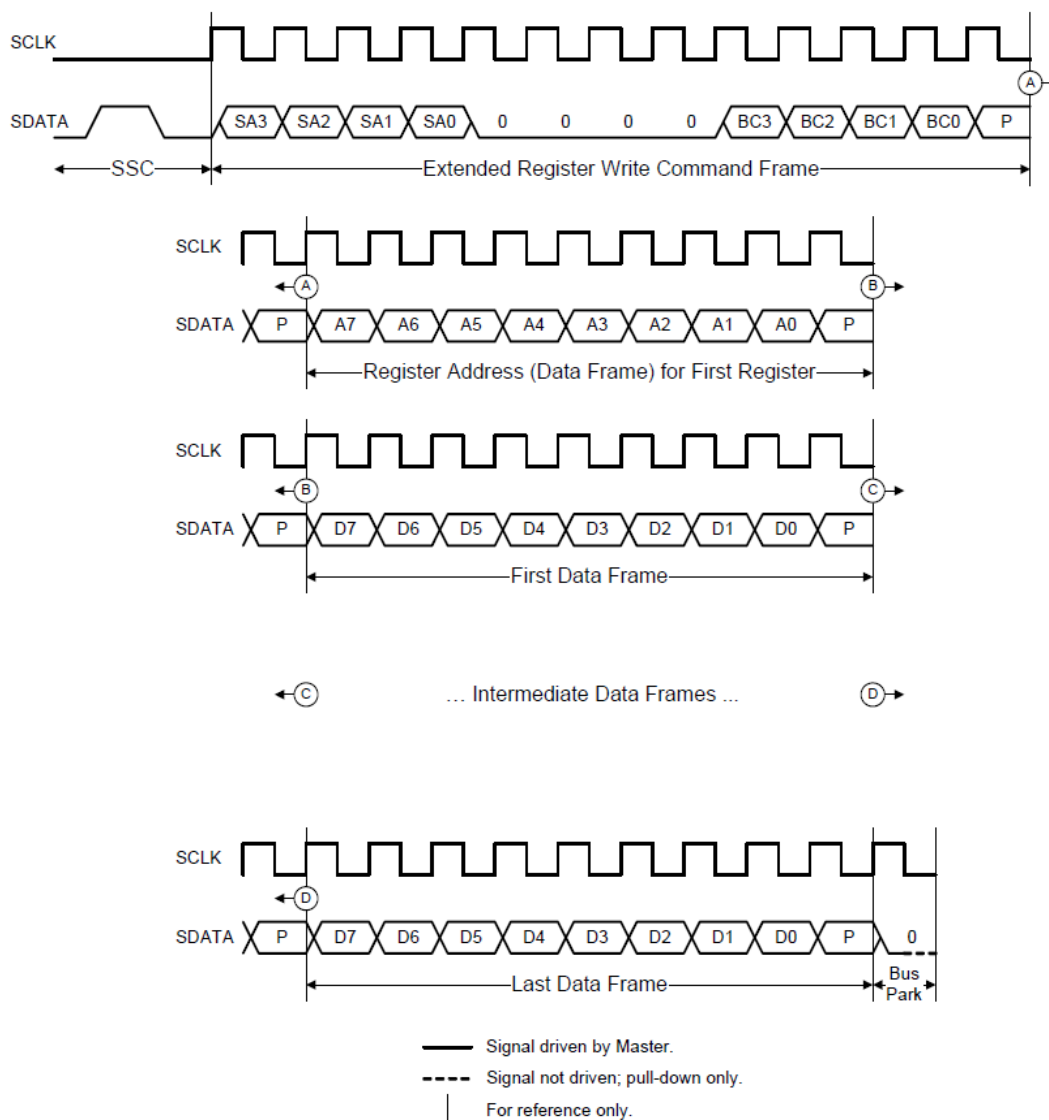


Figure 14. Extended Register Write Command Sequence

Table 27. EXTENDED REGISTER WRITE TO UPDATE DAC A, B, C (Note 6)

| Description | SSC | | Command Frame | | | | | | | | | | Address Frame | | | | | | | | | | | | |
|--|-----|---|---------------|--|--|---|---------|---|---|--------------|---|---|---------------|---|--------------------|---|---|---|---|---|---|---|---|--|---|
| Extended Register Write TC_IND _X _L and DAC A, B, C | | | | | | | Op Code | | | <Byte Count> | | | | P | <Starting Address> | | | | | | | | | | P |
| | 1 | 0 | SA [3,0] | | | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | P | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | P | | |

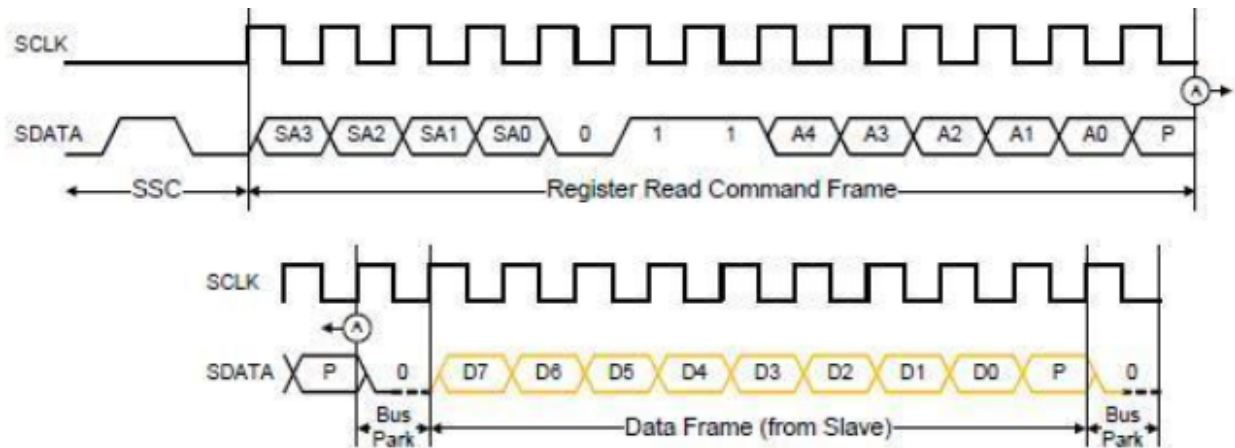
| Data Frame | | Data Frame | | | | Data Frame | | | | Data Frame | | | | BP | | | |
|--------------|---|--------------|--|--|--|------------|--------------|--|--|------------|---|--------------|--|----|--|---|----|
| <Data 8-bit> | P | <Data 8-bit> | | | | P | <Data 8-bit> | | | | P | <Data 8-bit> | | | | P | BP |
| Turbo-Charge | P | DAC_A [7,0] | | | | P | DAC_B [7,0] | | | | P | DAC_C [7,0] | | | | P | BP |

Table 28. EXTENDED REGISTER WRITE TO UPDATE DAC D, E, F (Note 6)

| Description | SSC | | Command Frame | | | | | | | | | | Address Frame | | | | | | | | | | | |
|--|-----|---|---------------|--|--|---------|---|---|--------------|---|---|---|---------------|--------------------|---|---|---|---|---|---|---|---|---|---|
| Extended Register Write TC_IND _X _U and DAC D, E, F | | | | | | Op Code | | | <Byte Count> | | | | P | <Starting Address> | | | | | | | | | | P |
| | 1 | 0 | SA [3,0] | | | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | P | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | P | |

| Data Frame | | Data Frame | | | | Data Frame | | | | Data Frame | | | | BP | | | | |
|--------------|--|------------|--------------|--|--|------------|---|--------------|--|------------|--|---|--------------|----|--|--|---|----|
| <Data 8-bit> | | P | <Data 8-bit> | | | | P | <Data 8-bit> | | | | P | <Data 8-bit> | | | | P | BP |
| Turbo-Charge | | P | DAC_D [7,0] | | | | P | DAC_E [7,0] | | | | P | DAC_F [7,0] | | | | P | BP |

6. The six DACs can be updated either all together in the same time by using one Extended Register Write command of 8 bytes, or separately by using two Extended Register Write commands of 4 bytes each, where one command is to update DAC A, B, C and the other command to update DAC D, E, F.

**Figure 15. Register Read Command Sequence****Table 29. REGISTER READ COMMAND**

| Description | SSC | | Command Frame | | | | | | | | | | |
|--------------------------------------|-----|---|---------------|---|---|---|---|---|---|---|---|---|----|
| Read MIPI-RFFE Status Register | 1 | 0 | SA[3:0] | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | P | BP |

| Description | Data Frame | | | | | | | | | |
|---|------------|------|-----|------|------|------|------|-----|----|--|
| Read MIPI-RFFE Status Register (Continued) | 0 | CFPE | CLE | AFPE | DFPE | RURE | WURE | BGE | BP | |

TCC-106

Following picture shows TCC-106 and all the necessary external components

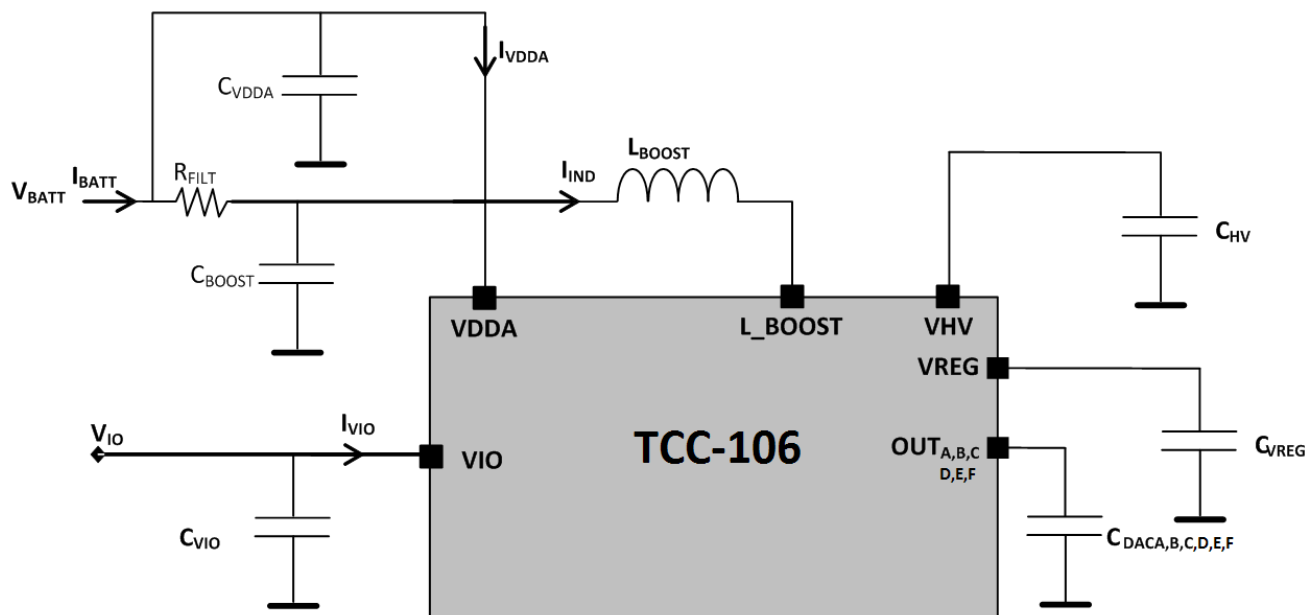


Figure 16. TCC-106 with External Components

Table 30. RECOMMENDED EXTERNAL BOM

| Component | Description | Nominal Value | Package | Recommended P/N |
|-----------------------------|---|---------------|---------|--|
| C _{BOOST} | Boost Supply Capacitor, 10 V | 1 μ F | 0402 | TDK: C1005X5R1A105K |
| L _{BOOST} | Boost Inductor | 15 μ H | 0603 | ABCO: LPS181210T-150M, Sunlord SPH201610H150MT |
| R _{FILT} | Filtering resistor, 5% | 3.3 ohms | 0402 | Vishay : CRCW04023R30JNED |
| C _{VIO} | V _{IO} Supply Decoupling, 10 V | 100 nF | 0201 | Murata: GRM033R61A104ME15D |
| C _{AVDD} | V _{AVDD} Supply Decoupling, 10 V | 1 μ F | 0402 | TDK: C1005X5R1A105K |
| C _{VREG} | V _{VREG} Supply Decoupling, 10 V | 220 nF | 0201 | TDK: C0603X5R1A224M |
| C _{HV} | Boost Tank Capacitor, 50 V | 47 nF | 1005 | Murata: GRM155C71H473KE19 |
| C _{dacA,B,C,D,E,F} | Decoupling Capacitor, 50 V (Note 7) | 100 pF | 0201 | Murata: GRM0335C1H101JD01D |

7. Recommended for noise reduction only – not essential

Mechanical Description: Ball Array Package

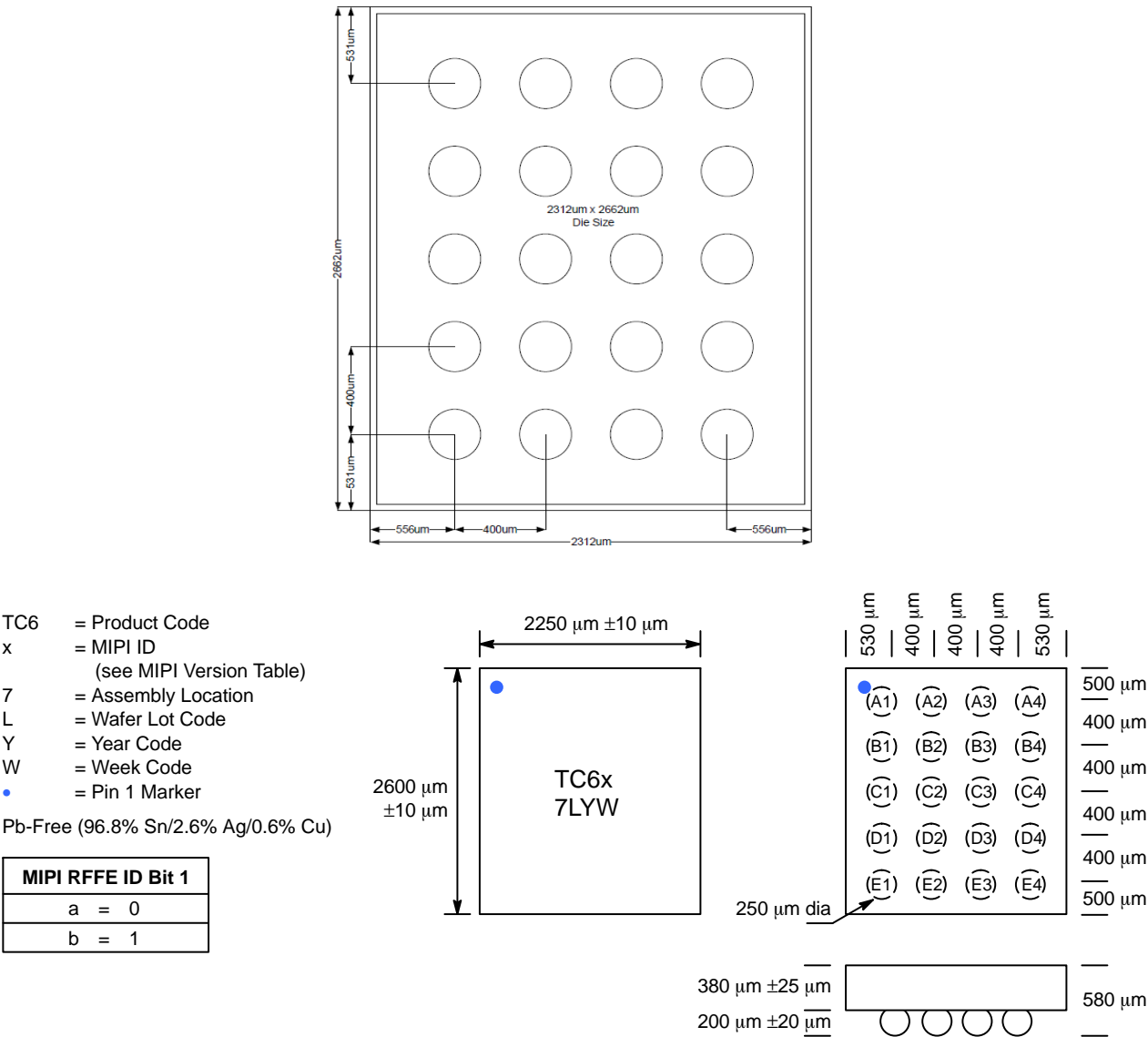


Figure 17. Ball Array Package – Top View

NOTE: Die dimensions include an assumed 60 µm wide sawing kerf, this kerf width is subject to change without notice.

TCC-106

Tape & Reel Dimensions

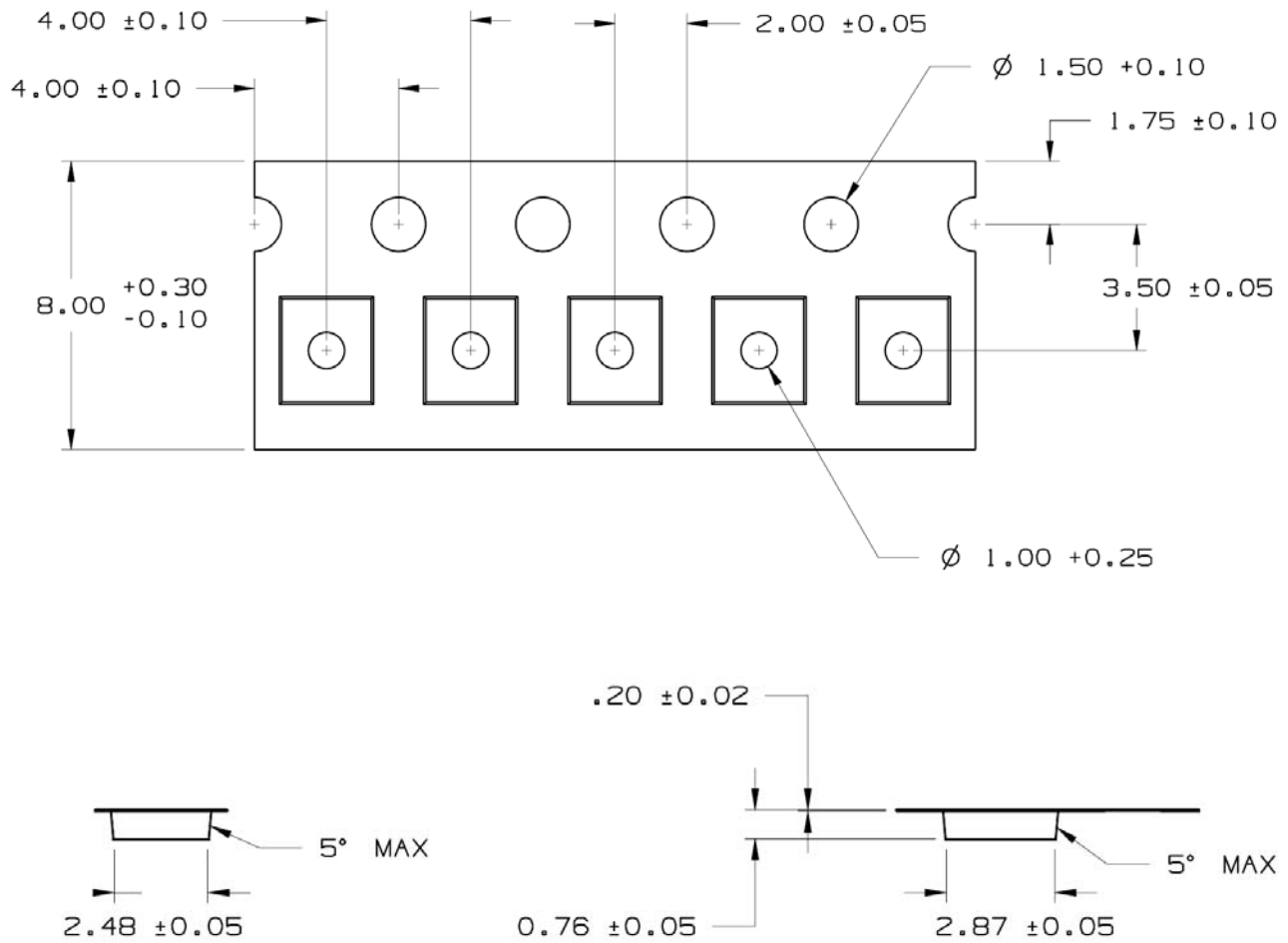


Figure 18. WLCSP Carrier Tape Drawings

Table 31. ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------|------------------|-----------------------|
| TCC-106A-RT | RDL (Pb-Free) | 3000 / Tape & Reel |
| TCC-106B-RT | RDL (Pb-Free) | 3000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

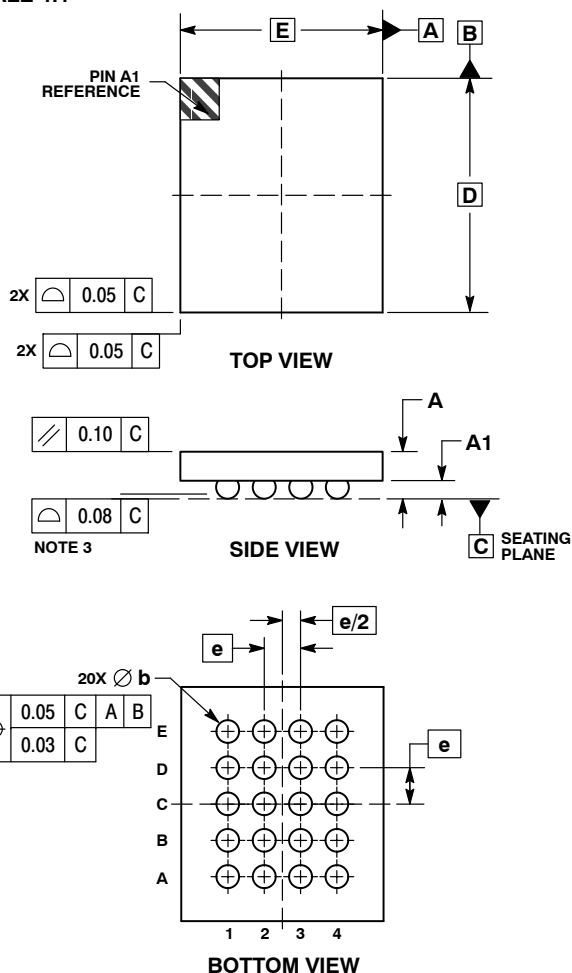
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SCALE 4:1

WLCSP20, 2.58x2.23
CASE 567HL
ISSUE A

DATE 03 MAR 2015

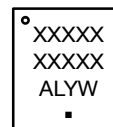


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

| DIM | MILLIMETERS | |
|-----|-------------|------|
| | MIN | MAX |
| A | --- | 0.65 |
| A1 | 0.17 | 0.23 |
| A3 | 0.38 REF | |
| b | 0.23 | 0.29 |
| D | 2.58 BSC | |
| E | 2.23 BSC | |
| e | 0.40 BSC | |

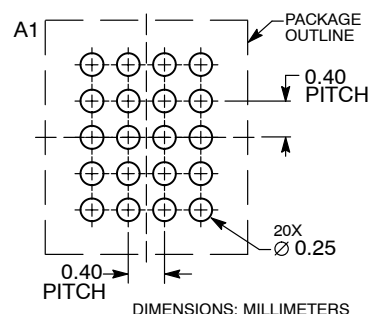
GENERIC MARKING DIAGRAM*



- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

| | | |
|-------------------------|---------------------------|--|
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